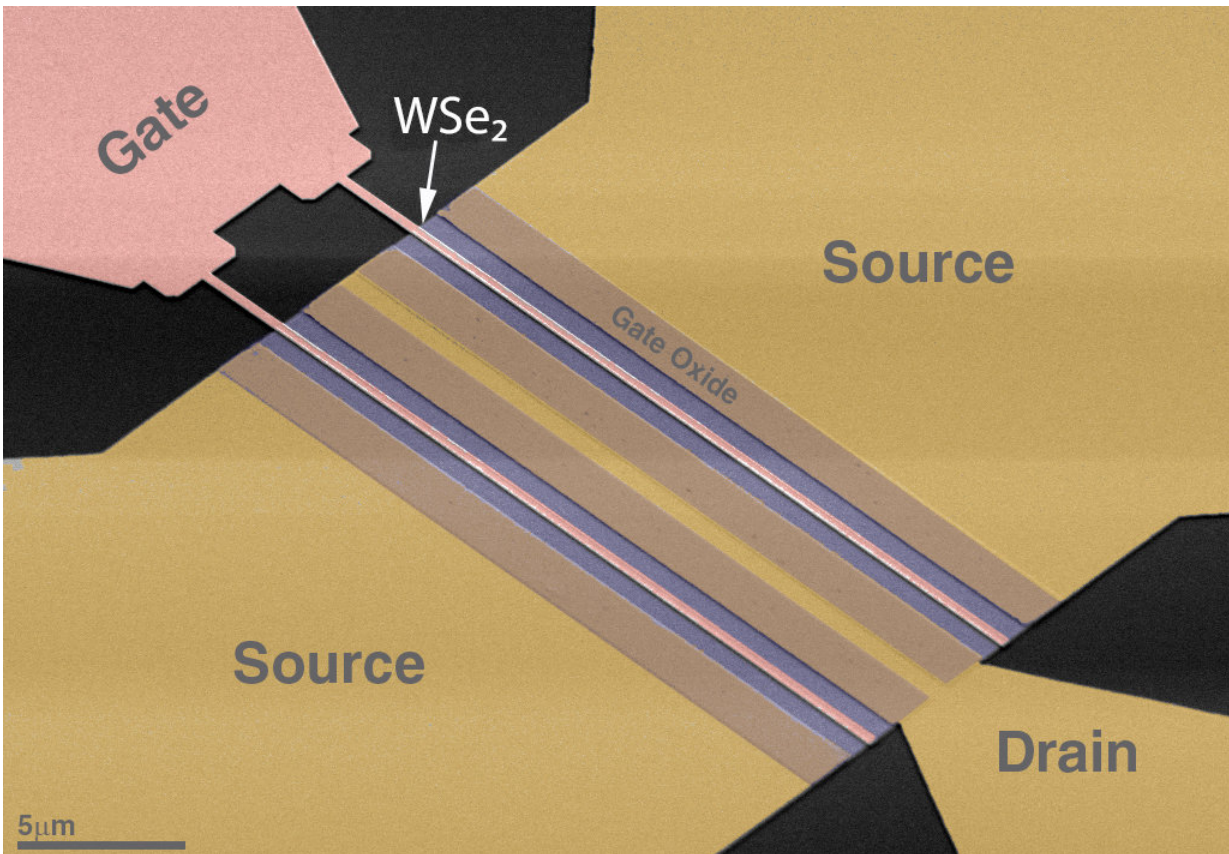


Scalable two-dimensional materials advance future-gen electronics

February 13 2018



False-colored scanning electron microscope (SEM) image of a radio-frequency field-effect transistor (RF-FET) composed of a 2-3 layer-thick epitaxially-grown tungsten diselenide (WSe₂) active channel. Credit: Brian Bersch/Penn State

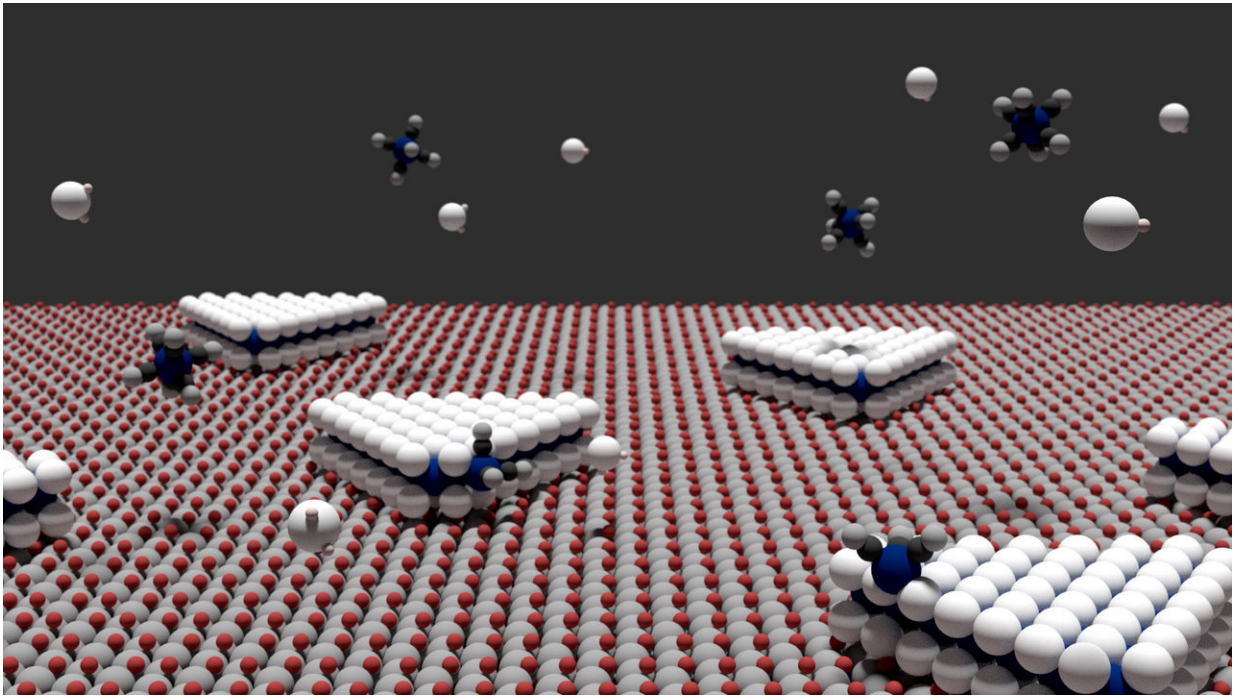
Since the discovery of the remarkable properties of graphene, scientists

have increasingly focused research on the many other two-dimensional materials possible, both those found in nature and concocted in the lab. However, growing high quality, crystalline 2-D materials at scale has proven a significant challenge.

A pair of papers published online in two nanotechnology journals this month provide the basis for growing wafer-scale two-dimensional crystals for future electronic devices. In work led by Joan Redwing, director of the NSF-sponsored Two-Dimensional Crystal Consortium – Materials Innovation Platform, and professor of [materials science](#) and engineering and electrical engineering, Penn State, researchers developed a multistep process to make single crystal atomically-thin films of tungsten diselenide across large-area sapphire substrates.

"Up until now, the majority of 2-D devices have been fabricated using small flakes that are exfoliated off of bulk crystals," Redwing said. "To develop a device-ready technology, you have to be able to make devices on large-area substrates and they have to have good crystal quality."

The process uses sapphire as the substrate because of its crystalline structure. This structure orients the film growth in a crystal pattern in a process called epitaxy. As small islands of the material form on the substrate and the substrate is heated, the islands spread out across the substrate in a uniform pattern forming a large-area film without gaps and with very few defects. The key advance was the use of gas source chemical vapor deposition to precisely control the island density and rate of spreading to achieve a single layer of the 2-D material.



Large-scale atomically-thin 2D films by gas source chemical vapor deposition.
Credit: Xiaotian Zhang/Penn State

They published their work, "Diffusion-Controlled Epitaxy of Large Area Coalesced WSe₂ Monolayers on Sapphire," in the journal *Nano Letters*.

In a related paper, "Realizing Large-Scale, Electronic-Grade Two-Dimensional Semiconductors," published online in the journal *ACS Nano*, a team led by Joshua Robinson, associate professor of [materials](#) science and engineering, Penn State, provides the foundational understanding to enable device-ready synthetic 2-D semiconductors based on these epitaxial large area films in future industrial-scale electronics.

"The primary significance of this work is we were able to achieve an understanding of the extrinsic factors that go into having a high-quality

2-D material," Robinson said. "What we found was that even when you grow oriented crystals on a surface, there are other factor that impact the ability to get high electron mobility or fast transistors."

In particular, they found that there is a strong interaction between the sapphire substrate and the monolayer film, with the substrate dominating the properties. To overcome these challenges, the researchers grew two or three layers, which improved the performance by factors of 20-100 times.

"This is the first real evidence of the effect of the [substrate](#) on the transport properties of 2-D layers," Robinson said.

More information: Yu-Chuan Lin et al. Realizing Large-Scale, Electronic-Grade Two-Dimensional Semiconductors, *ACS Nano* (2018).

[DOI: 10.1021/acsnano.7b07059](https://doi.org/10.1021/acsnano.7b07059)

Xiaotian Zhang et al. Diffusion-Controlled Epitaxy of Large Area Coalesced WSe₂ Monolayers on Sapphire, *Nano Letters* (2018). [DOI:](#)

[10.1021/acs.nanolett.7b04521](https://doi.org/10.1021/acs.nanolett.7b04521)

Provided by Pennsylvania State University

Citation: Scalable two-dimensional materials advance future-gen electronics (2018, February 13) retrieved 2 May 2024 from

<https://phys.org/news/2018-02-scalable-two-dimensional-materials-advance-future-gen.html>

<p>This document is subject to copyright. Apart from any fair dealing for the purpose of private study or research, no part may be reproduced without the written permission. The content is provided for information purposes only.</p>
--